



DMT5015LFDF

Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
50V	15mΩ @ V _{GS} = 10V	9.1A
500	23mΩ @ V _{GS} = 4.5V	7.4A

50V N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- 0.6mm Profile Ideal for Low Profile Applications
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

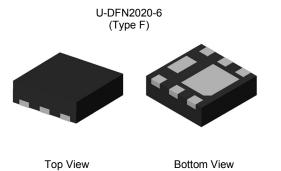
Description and Applications

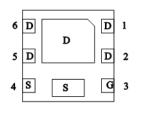
This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- Load Switch
- Adaptor Switch
- Notebook PC

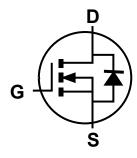
Mechanical Data

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.007 grams (Approximate)





Pin Out Bottom View



Internal Schematic

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Quantity per Reel
DMT5015LFDF-7	T5	7	3000
DMT5015LFDF-13	T5	13	10,000

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.



Marking Information

Site 1:



T5 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: H = 2020) M = Month (ex: 9 = September)

Year	2013		2019	2020	2021	2022	2023	2024	2025	2026	2027	2028
Code	А		G	Н	I	J	К	L	М	N	0	Р
Month	ı .	lan Fo	eb Ma	r Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec

Site 2:



T5 = Product Type Marking Code YWX = Date Code Marking

Y = Year (ex: H = 2020)W = Week (ex: a = week 27; z represents week 52 and 53) X = Internal code (ex: U = Monday)

Date Code Key										
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	
Code	0	1	2	3	4	5	6	7	8	
Week	1-26				27-52			53		
Code		A-Z			a-z			z		
Internal Code	Sun	Mon		Tue	Wed	Thu		Fri	Sat	
Code	Т	U		V	W	Х		Y	Z	



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	50	V		
Gate-Source Voltage	V _{GSS}	±16	V		
	Steady State	T _A = +25°C T _A = +70°C	ID	9.1 7.3	А
Continuous Drain Current (Note 6) V_{GS} = 10V	t<10s	T _A = +25°C T _A = +70°C	ID	11.5 9.2	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	6)		I _{DM}	60	А
Continuous Source-Drain Diode Current	T _A = +25°C	Is	2.2	А	
Avalanche Current (Note 7) L = 0.1mH		IAS	14.4	А	
Avalanche Energy (Note 7) L = 0.1mH			E _{AS}	10.4	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units	
Total Dower Dissinction (Note 5)	T _A = +25°C	P	0.82	W	
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.52	vv	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	P	153	°C/W	
member (Note 5)	t<10s	R _{0JA}	96		
Total Power Dissipation (Note 6)	T _A = +25°C	P	1.97	W	
Total Power Dissipation (Note 6)	T _A = +70°C	PD	1.2		
Thermal Desistance Junction to Ambient (Note 6)	Steady State	D	67	°C/W	
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{\theta JA}$	42		
Thermal Resistance, Junction to Case (Note 6)	Steady State	R _{θJC}	14		
Operating and Storage Temperature Range		TJ. TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						•
Drain-Source Breakdown Voltage	BV _{DSS}	50	—	—	V	V _{GS} = 0V, I _D = 250µA
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	—	1	μA	V _{DS} = 40V, V _{GS} = 0V
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 16V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						-
Gate Threshold Voltage	V _{GS(TH)}	0.5	—	2.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Static Drain-Source On-Resistance			10.5	15	mΩ	V _{GS} = 10V, I _D = 8A
	R _{DS(ON)}	—	14	23	11122	V _{GS} = 4.5V, I _D = 6A
Diode Forward Voltage	V _{SD}	—	0.7	1.0	V	V _{GS} = 0V, I _S = 5A
DYNAMIC CHARACTERISTICS (Note 9)						-
Input Capacitance	C _{ISS}	—	902.7	_		V _{DS} = 25V, V _{GS} = 0V, f = 1.0MHz
Output Capacitance	C _{OSS}	—	301.4	_	pF	
Reverse Transfer Capacitance	C _{RSS}	—	15.2	—		1 - 1.00012
Gate Resistance	R _G	—	1.9	—	Ω	V_{DS} = 0V, V_{GS} = 0V, f = 1MHz
Total Gate Charge (V _{GS} = 4.5V)	Q _G	—	6.1	—		
Total Gate Charge (V _{GS} = 10V)	Q _G	—	14	—	nC	
Gate-Source Charge	Q _{GS}	_	2.4	—	nc	$V_{DS} = 25V, I_D = 8A$
Gate-Drain Charge	Q _{GD}	—	1.6	—		
Turn-On Delay Time	t _{D(ON)}	_	2.8	—		
Turn-On Rise Time	t _R	_	5.1			V _{DS} = 25V, V _{GS} = 10V,
Turn-Off Delay Time	t _{D(OFF)}		10.6		ns	$R_G = 3\Omega$, $I_D = 8A$
Turn-Off Fall Time	t _F	_	2.7	—	1	
Reverse Recovery Time	t _{RR}	—	18.9	—	ns	I _F = 8A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}		9.2		nC	I _F = 8A, di/dt = 100A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

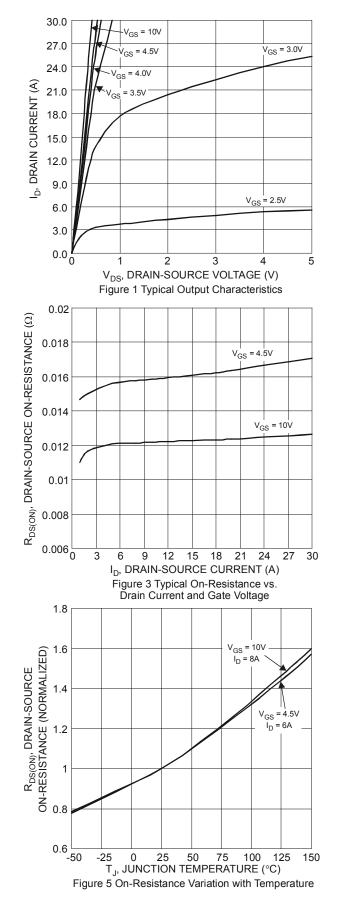
7. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C.

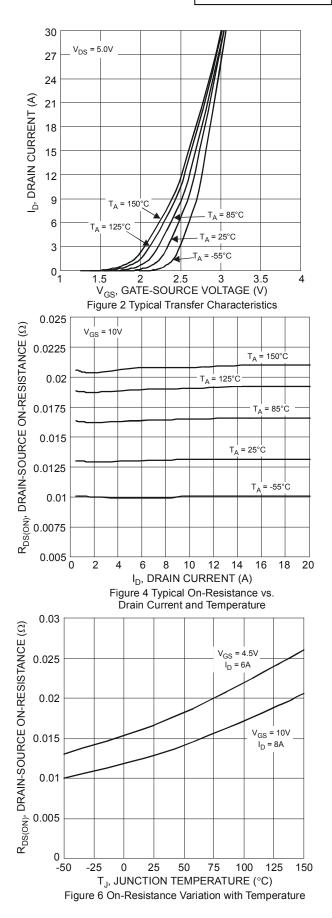
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to product testing.



DMT5015LFDF







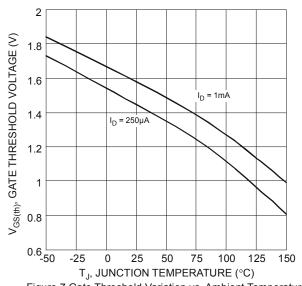


Figure 7 Gate Threshold Variation vs. Ambient Temperature

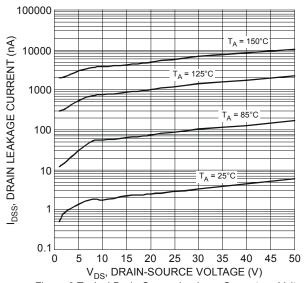
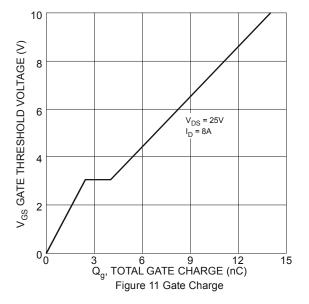
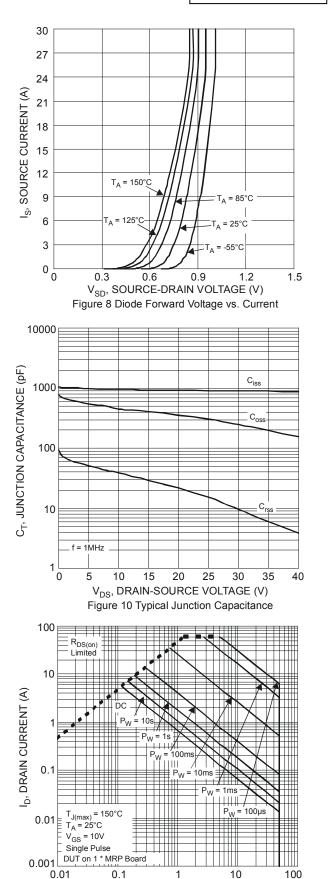


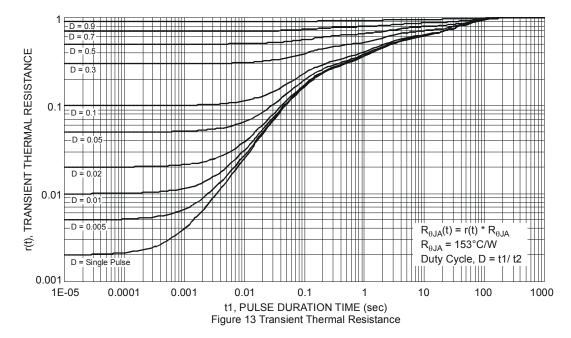
Figure 9 Typical Drain-Source Leakage Current vs. Voltage





V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12 SOA, Safe Operation Area

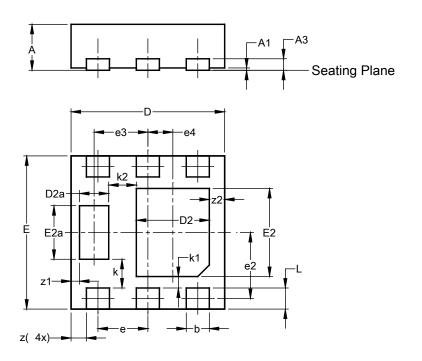






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



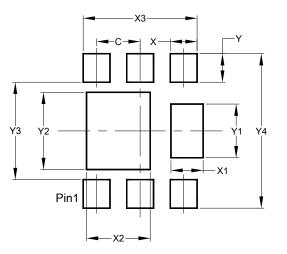
U-DFN2020-6	(Type F)
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		2020-6 De F)	
Dim	Min	Max	Тур
Α	0.57	0.63	0.60
A1	0.00	0.05	0.03
A3	-	-	0.15
b	0.25	0.35	0.30
D	1.95	2.05	2.00
D2	0.85	1.05	0.95
D2a	0.33	0.43	0.38
E	1.95	2.05	2.00
E2	1.05	1.25	1.15
E2a	0.65	0.75	0.70
е		0.65 BS	С
e2	0).863 BS	SC
e3		0.70 BS	С
e4	0).325 BS	SC
k		0.37 BS	-
k1		0.15 BS	С
k2		0.36 BS	
L		0.325	
z		0.20 BS	-
z1).110 BS	
z2		0.20 BS	-
	Dimens	ions in	mm

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN2020-6 (Type F)



Dimensions	Value
	(in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300



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